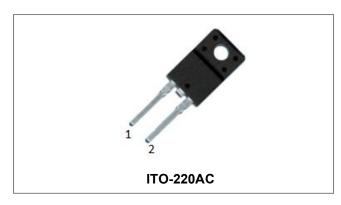


SDURF860

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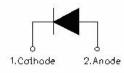
SDURF860 ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	8	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	110	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@8A, Pulse, T」= 25°C	1.3	1.7	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$, T _J = 25°C	0.3	5	μA
	I _{R2}	$@V_R = rated V_R$, T _J = 125°C	84	500	μA
Reverse Recovery Time	t _{rr}	I_F =500mA, I_R =1A,and I_m =250mA	42	50	ns

* Pulse width < 300 μs, duty cycle < 2%

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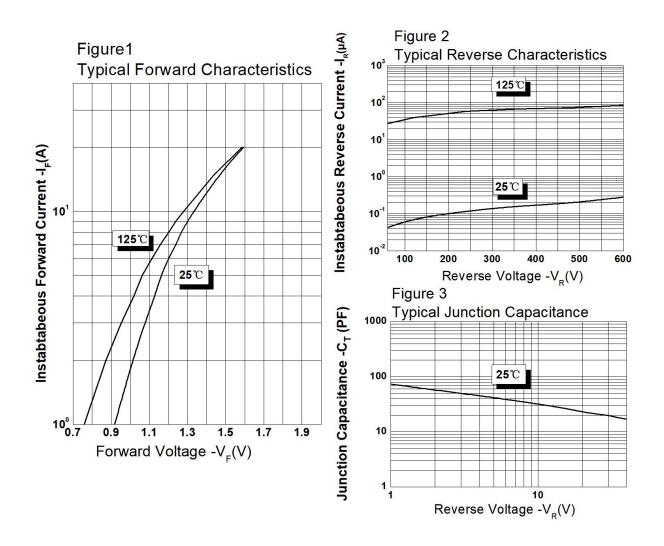


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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	R _{0JA}	DC operation	25	°C/W
Approximate Weight	wt	-	1.65	g
Case Style	ITO-220AC			

Ratings and Characteristics Curves



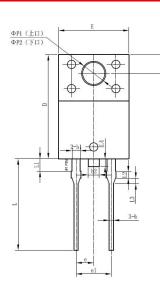


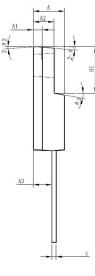
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Mechanical Dimensions ITO-220AC

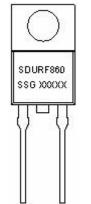
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CYMPOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
A	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
с	0.55	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е	-	2.55	-	
e1	-	5.10	-	
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
L4	-	1.10	1.50	
ΦΡ1(上口)	3.30	3.50	3.70	
ΦΡ2 (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

Marking Diagram



Where XXXXX is YYWWL

- = Device Type SDUR
 - = Package type = Forward Current (8A) = Reverse Voltage (600V)
 - - = SSG
 - = Year
 - = Week
 - = Lot Number

Cautions: Molding resin

Ordering Information:

Device	Package	Shipping
SDURF860	ITO-220AC (Pb-Free)	50 pcs/ tube

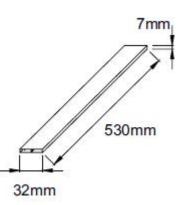
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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Tube Specification



where A	
	_

60

YY

WW

L

- F 8
- SSG

Epoxy resin UL:94V-0





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